NSN 5961-01-309-3403

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-309-3403 **Inclosure Material:** Plastic **Overall Length:** 0.190 inches **Terminal Length:** 0.500 inches **Overall Height:** 0.670 inches **Overall Width:** 0.145 inches **Function For Which Designed:** Voltage reference Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-92 **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1.247 reverse breakdown voltage, dc **Current Rating Per Characteristic:** 30.00 milliamperes forward current, average peak and 10.00 milliamperes source cutoff current preset **Maximum Operating Tempurature Per Measurement Point:** 70.0 degrees celsius junction **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No